

DSS4160V

LOW V_{CE(SAT)} NPN SURFACE MOUNT TRANSISTOR

Features

- **Epitaxial Planar Die Construction**
- Complementary PNP Type Available (DSS5160V)
- Low Collector-Emitter Saturation Voltage, V_{CE(SAT)}
- Surface Mount Package Suited for Automated Assembly
- Ultra-Small Surface Mount Package
- Lead Free/RoHS Compliant (Note 1)
- "Green Device" (Note 2)

Mechanical Data

Case: SOT-563

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- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020D •
- Terminals: Finish Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208
- Marking Information: See Page 4
- Ordering Information: See Page 4
- Weight: 0.003 grams (approximate)









Top View

Bottom View

Device Schematic

Pin Out Configuration

Maximum Ratings $@T_A = 25^{\circ}C$ unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	80	V
Collector-Emitter Voltage	V _{CEO}	60	V
Emitter-Base Voltage	V _{EBO}	5	V
Collector Current - Continuous	lc	1	А
Peak Pulse Collector Current	I _{CM}	2	А
Base Current (DC)	I _B	300	mA
Peak Base Current	I _{BM}	1	A

Thermal Characteristics

		-	
Characteristic	Symbol	Value	Unit
Power Dissipation (Note 3) @ $T_A = 25^{\circ}C$	PD	600	mW
Thermal Resistance, Junction to Ambient (Note 3) @ $T_A = 25^{\circ}C$	$R_{ heta}JA$	208	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	⊃°

Notes: No purposefully added lead. 1.

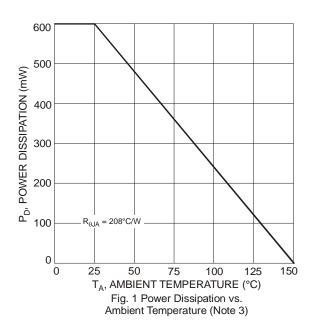
Diode's Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.
Device mounted on FR-4 PCB with minimum recommended pad layout.

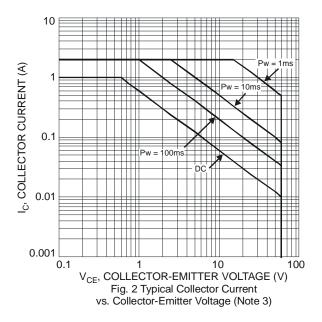


Electrical Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS	Cymbol		.,,,	max	•		
Collector-Base Breakdown Voltage	V _{(BR)CBO}	80		_	V	$I_{\rm C} = 100 \mu A, I_{\rm E} = 0$	
Collector-Emitter Breakdown Voltage (Note 4)	V _{(BR)CEO}	60		_	V	$I_{\rm C} = 10 {\rm mA}, I_{\rm B} = 0$	
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	5	_		V	$I_{E} = 100 \mu A, I_{C} = 0$	
Collector Cutoff Current	I _{CBO}	_	_	100 50	nA μA	V _{CB} = 60V, I _E = 0 V _{CB} = 60V, I _E = 0, T _A = 150°C	
Collector Cutoff Current	I _{CES}	_		100	nA	$V_{CE} = 60V, V_{BE} = 0$	
Emitter Cutoff Current	I _{EBO}			100	nA	$V_{EB} = 5V, I_{C} = 0$	
ON CHARACTERISTICS (Note 4)						· · ·	
DC Current Gain	h _{FE}	250 200 100			_	$V_{CE} = 5V, I_C = 1mA$ $V_{CE} = 5V, I_C = 500mA$ $V_{CE} = 5V, I_C = 1A$	
Collector-Emitter Saturation Voltage	V _{CE(SAT)}			110 140 250	mV	$I_{C} = 100$ mA, $I_{B} = 1$ mA $I_{C} = 500$ mA, $I_{B} = 50$ mA $I_{C} = 1$ A, $I_{B} = 100$ mA	
Collector-Emitter Saturation Resistance	R _{CE(SAT)}	_		250	mΩ	$I_{\rm C} = 1$ A, $I_{\rm B} = 100$ mA	
Base-Emitter Saturation Voltage	V _{BE(SAT)}			1.1	V	$I_{\rm C} = 1$ A, $I_{\rm B} = 50$ mA	
Base-Emitter Turn On Voltage	V _{BE(ON)}	_	_	0.9	V	$V_{CE} = 5V, I_{C} = 1A$	
SMALL SIGNAL CHARACTERISTICS							
Output Capacitance	C _{obo}	_	—	10	pF	V _{CB} = 10V, f = 1.0MHz	
Current Gain-Bandwidth Product	fT	150	—	_	MHz	$V_{CE} = 10V, I_C = 50mA, f = 100MHz$	
SWITCHING CHARACTERISTICS						-	
Turn-On Time	t _{on}	_	68	_	ns		
Delay Time	t _d	_	31	_	ns		
Rise Time	tr	_	37		ns	$V_{CC} = 10V$	
Turn-Off Time	t _{off}		430		ns	$I_{C} = 0.5A, I_{B1} = I_{B2} = 25mA$	
Storage Time	ts		383		ns		
Fall Time	t _f	_	47	_	ns]	

Notes: 4. Measured under pulsed conditions. Pulse width = 300μ s. Duty cycle $\leq 2\%$.

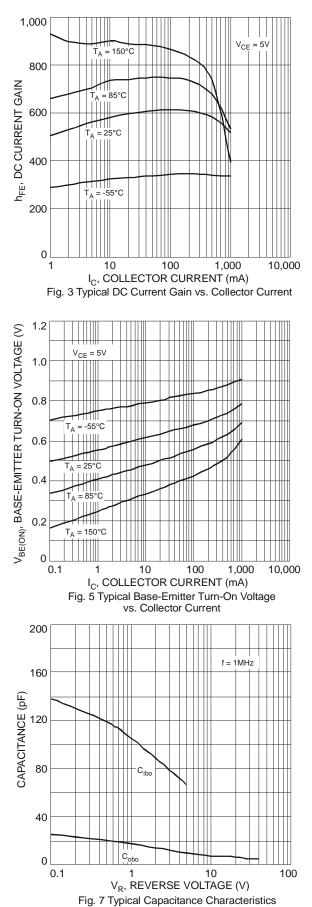


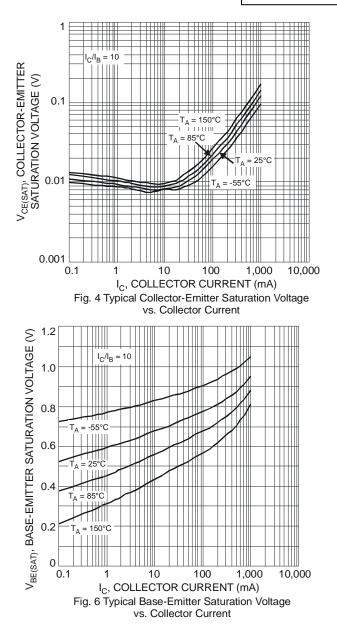




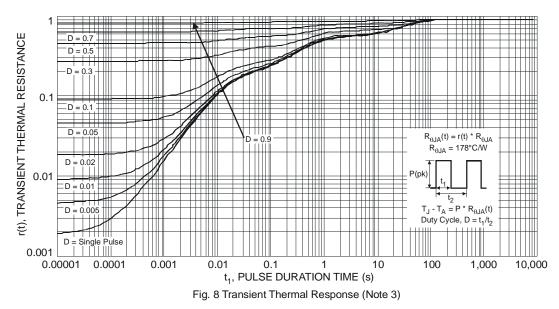
NEW PRODUCT

DSS4160V





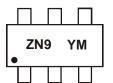




Ordering Information (Note 5)		
Part Number	Case	Packaging
DSS4160V-7	SOT-563	3000/Tape & Reel

Notes: 5. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

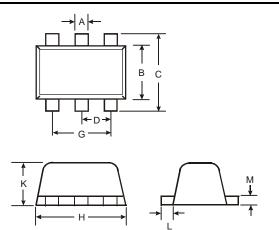
Marking Information



ZN9 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: V = 2008) M = Month (ex: 9 = September)

Date Code Key												
Year	2008		2009	2010		2011	2012		2013	2014		2015
Code	V		W	Х		Y	Z		А	В		С
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

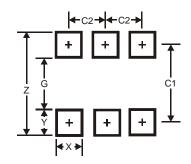
Package Outline Dimensions



SOT-563						
Dim	Min	Max	Тур			
Α	0.15	0.30	0.20			
В	1.10	1.25	1.20			
С	1.55	1.70	1.60			
D	-	-	0.50			
G	0.90	1.10	1.00			
Н	1.50	1.70	1.60			
Κ	0.55	0.60	0.60			
L	0.10	0.30	0.20			
Μ	0.10	0.18	0.11			
All	All Dimensions in mm					



Suggested Pad Layout



Dimensions	Value (in mm)
Z	2.2
G	1.2
Х	0.375
Y	0.5
C1	1.7
C2	0.5

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